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Contents

v Conference Committee

SESSION 1	QUANTUM DOT AND NOVEL DEVICES
6779 03	Strain-compensated quantum dots emitting at 1.5 micron: resonant nonlinear optical properties and exciton dynamics (Invited Paper) [6779-02] J. Ishi-Hayase, K. Akahane, N. Yamamoto, National Institute of Information and Communications Technology (Japan); M. Kujiraoka, National Institute of Information and Communications Technology (Japan) and Sophia Univ. (Japan); K. Ema, Sophia Univ. (Japan); M. Sasaki, National Institute of Information and Communications Technology (Japan)
6779 04	1.55-µm range InAs/InP (100) quantum dot telecom devices (Invited Paper) [6779-03] R. Nötzel, S. Anantathanasarn, P. J. van Veldhoven, Y. Barbarin, E. A. J. M. Bente, M. K. Smit, Eindhoven Univ. (Netherlands); N. I. Cade, H. Kamada, NTT Corp. (Japan); B. Satpati, A. Trampert, Paul Drude Institute for Solid State Electronics (Germany)
6779 05	Recent progress in self-assembled quantum-dot optical devices (Invited Paper) [6779-04] M. Henini, Univ. of Nottingham (United Kingdom)
6779 06	Progress in developing nanophotonic devices driven by optical near-field (Invited Paper) [6779-05] T. Yatsui, Japan Science and Technology Agency (Japan); GC. Yi, POSTECH (South Korea); M. Ohtsu, Japan Science and Technology Agency (Japan) and Univ. of Tokyo (Japan)
SESSION 2	QUANTUM DOT/NANOSTRUCTURE AND NOVEL DEVICES
6779 08	High performance long wavelength quantum dot lasers on GaAs (Invited Paper) [6779-07] P. Bhattacharya, Z. Mi, Univ. of Michigan (USA)
SESSION 3	NOVEL DEVICES TECHNOLOGY
6779 OB	Optoelectronic properties of organic-inorganic hybrid systems for sensing applications (Invited Paper) [6779-10] M. Dutta, M. A. Stroscio, Univ. of Illinois/Chicago (USA)
6779 0D	Novel nanostructures quantum dot based devices (Invited Paper) [6779-12] S. Loualiche, A. LeCorre, J. Even, INSA-Rennes (France); J. C. Simon, ENSSAT (France); A. Ramdane, CNRS-LPN (France)

6779 0E Randomly oriented indium phosphide nanowires for optoelectronics (Invited Paper)

N. P. Kobayashi, Univ. of California/Santa Cruz (USA) and Hewlett-Packard Labs. (USA); V. J. Logeeswaran, Univ. of California/Davis (USA); X. Li, Hewlett-Packard Labs. (USA); M. S. Islam, Univ. of California/Davis (USA); J. Straznicky, S.-Y. Wang, R. S. Williams, Hewlett-Packard Labs. (USA)

SESSION 4 PHOTONIC CRYSTAL-BASED NOVEL DEVICES

- 6779 0G **Photonic crystal nanocavity lasers with quantum dots (Invited Paper)** [6779-15] M. Nomura, S. Iwamoto, Y. Arakawa, The Univ. of Tokyo (Japan)
- 6779 OH

 Dispersion compensator based on multiple 1D coupled-defect-type photonic crystals (Invited Paper) [6779-16]

 M. Sagawa, S. Goto, K. Hosomi, Univ. of Tokyo (Japan), Hitachi Ltd. (Japan), and

M. Sagawa, S. Goto, K. Hosomi, Univ. of Tokyo (Japan), Hitachi Ltd. (Japan), and Optoelectronic Industry and Technology Development Association (Japan); T. Sugawara, Hitachi Ltd. (Japan) and Optoelectronic Industry and Technology Development Association (Japan); T. Katsuyama, Univ. of Tokyo (Japan) and Optoelectronic Industry and Technology Development Association (Japan); Y. Arakawa, Univ. of Tokyo (Japan)

- 6779 01 Printed second harmonic active organic nanofiber arrays [6779-17]
 F. Balzer, J. Brewer, J. Kjelstrup-Hansen, M. Madsen, M. Schiek, Univ. of South Denmark (Denmark); K. Al-Shamery, Univ. of Oldenburg (Germany); A. Lützen, Univ. of Bonn (Germany); H.-G. Rubahn, Univ. of South Denmark (Denmark)
- Hole assisted fibers (HAFs) and holey fibers (HFs) for short-wavelength applications (Invited Paper) [6779-18]
 K. Mukasa, R. Miyabe, K. Imamura, K. Aiso, R. Sugizaki, T. Yagi, Furukawa Electric Co., Ltd. (Japan)
- 6779 OK InP nanowire photodetectors heteroepitaxially grown between silicon electrodes [6779-19]
 A. Sarkar, A. Chaudhry, V. J. Logeeswaran, Univ. of California/Davis (USA); S. Yi, Philips
 Lumileds Lighting Co. (USA); M. S. Islam, Univ. of California/Davis (USA)

Author Index

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- Quantum Dot and Novel Devices
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- Quantum Dot/Nanostructure and Novel Devices Junko Ishi-Hayase, National Institute of Information and Communications Technology (Japan) Achyut Kumar Dutta, Banpil Photonics, Inc. (USA)

- Novel Devices Technology
 Nibir K. Dhar, Army Research Laboratory (USA)
 Ahalapitiya Hewage Jayatissa, University of Toledo (USA)
- Photonic Crystal-based Novel Devices
 Junko Ishi-Hayase, National Institute of Information and Communications Technology (Japan)
 Nibir K. Dhar, Army Research Laboratory (USA)
- Special Session on Opportunities in Nanotechnology II
 Nobuhiko P. Kobayashi, University of California/Santa Cruz (USA)
 M. Saif Islam, University of California/Davis (USA)